P64LF6QNK

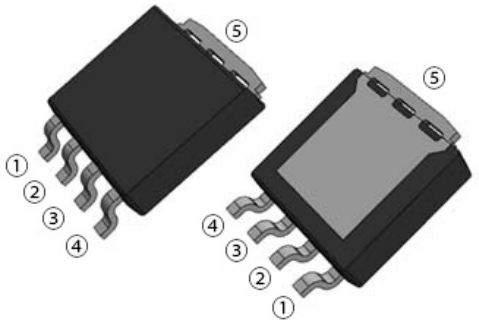
Power MOSFETs
60V, 64A, N-channel

Feature

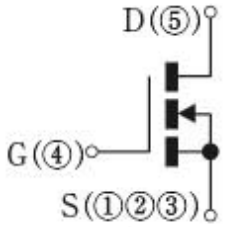
- N-channel
- Small SMD
- Large Current
- Low Ron
- 10V Gate Drive
- Low Capacitance
- Based on AEC-Q101
- Halogen free
- Pb free terminal
- RoHS:Yes

OUTLINE

Package (House Name): LF
Package (JEDEC Code): MO-235B similar



Equivalent circuit



Absolute Maximum Ratings (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings	Unit
Storage temperature	Tstg		-55 to 175	°C
Channel tempertature	Tch		-55 to 175	°C
Drain-source voltage	V_{DSS}		60	V
Gate-source voltage	V_{GSS}		±20	V
Continuous drain current(DC)	I_D		64	A
Continuous drain current(Peak)	I_{DP}	Pulse width 10μs, duty=1/100	192	A
Total power dissipation	P_T		168	W
Single avalanche current	I_{AS}	Starting Tch=25°C Tch≦150°C	34	A
Single avalanche energy	E_{AS}	Starting Tch=25°C Tch≦150°C	128	mJ

※ ：See the original Specifications

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Electrical Characteristics (unless otherwise specified : Tc=25°C)

Item	Symbol	Conditions	Ratings			Unit
			MIN	TYP	MAX	
Drain-Source breakdown voltage	$V_{(BR)DSS}$	ID=1mA, VGS=0V	60			V
Zero gate voltage drain current	I_{DSS}	VDS=60V, VGS=0V			1	μA
Gate-source leakage current	I_{GSS}	VGS=±20V, VDS=0V			±0.1	μA
Forward transconductance	g_{fs}	ID=32A, VDS=10V	10			S
Static drain-source on-state resistance	$R_{DS(ON)}$	ID=32A, VGS=10V		0.0045	0.0057	Ω
Gate threshold voltage	Vth	ID=1mA, VDS=10V	2	3	4	V
Source-drain diode forward voltage	V_{SD}	IS=64A, VGS=0V			1.5	V
Thermal resistance	Rth(j-c)	Junction to case, with heatsink			0.89	°C/W
Total gate charge	Qg	VDD=48V, VGS=10V, ID=64A		61		nC
Gate to source charge	Qgs	VDD=48V, VGS=10V, ID=64A		18		nC
Gate to drain charge	Qgd	VDD=48V, VGS=10V, ID=64A		22		nC
Input capacitance	Ciss	VDS=25V, VGS=0V, f=1MHz		3540		pF
Reverce transfer capacitnce	Crss	VDS=25V, VGS=0V, f=1MHz		160		pF
Output capacitance	Coss	VDS=25V, VGS=0V, f=1MHz		365		pF
Turn-on delay time	td(on)	ID=32A, RL=0.94Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		6.5		ns
Rise time	tr	ID=32A, RL=0.94Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		19		ns
Turn-off delay time	td(off)	ID=32A, RL=0.94Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		45		ns
Fall time	tf	ID=32A, RL=0.94Ω, VDD=30V, Rg=0Ω, VGS(+)=10V, VGS(-)=0V		19		ns
Diode reverse recovery time	trr	IF=64A, VGS=0V, di/dt=100A/μs		42		ns
Diode reverse recovery charge	Qrr	IF=64A, VGS=0V, di/dt=100A/μs		51		nC

※ ：See the original Specifications

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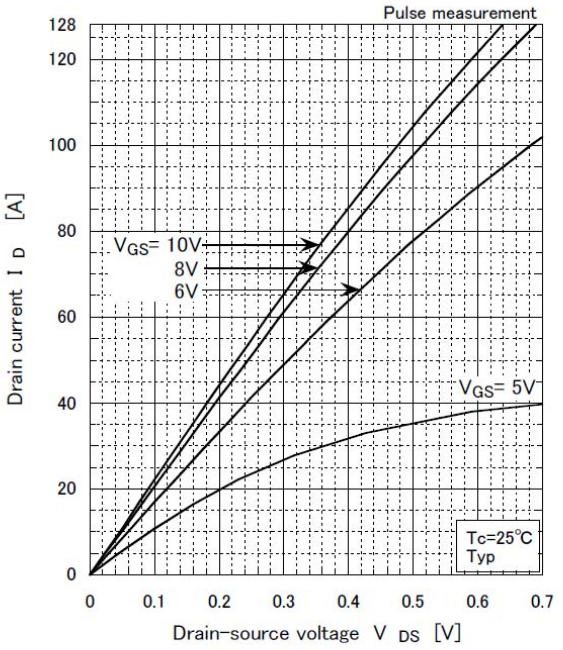
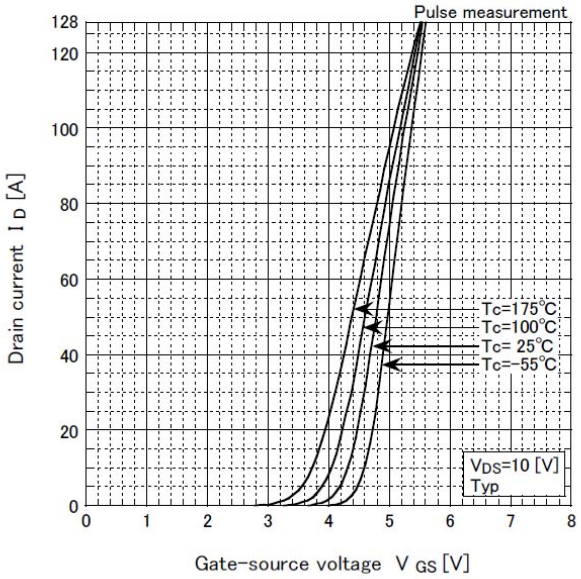
CHARACTERISTIC DIAGRAMS

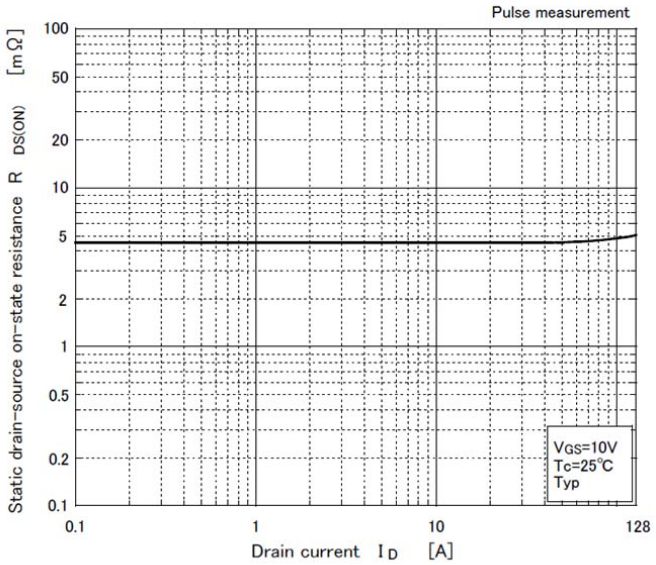
Typical output characteristics



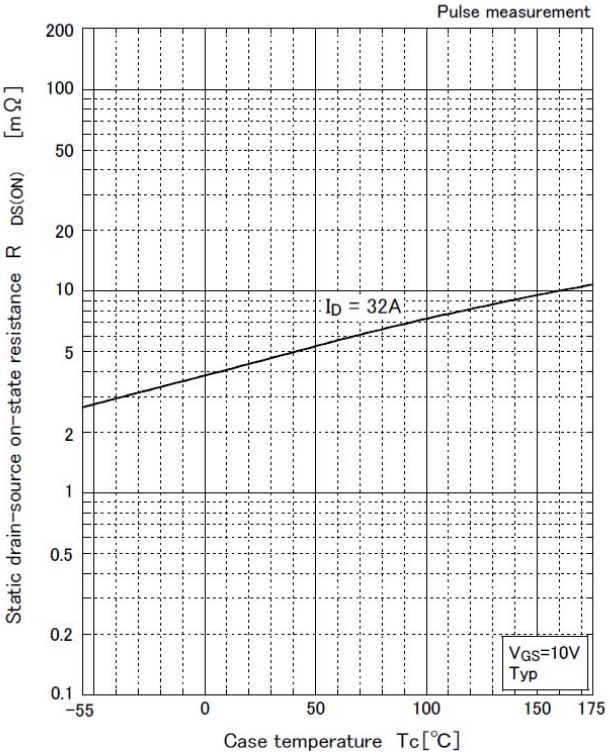
Transfer characteristics



Static drain-source on-state resistance vs drain current



Static drain-source on-state resistance vs case temperature



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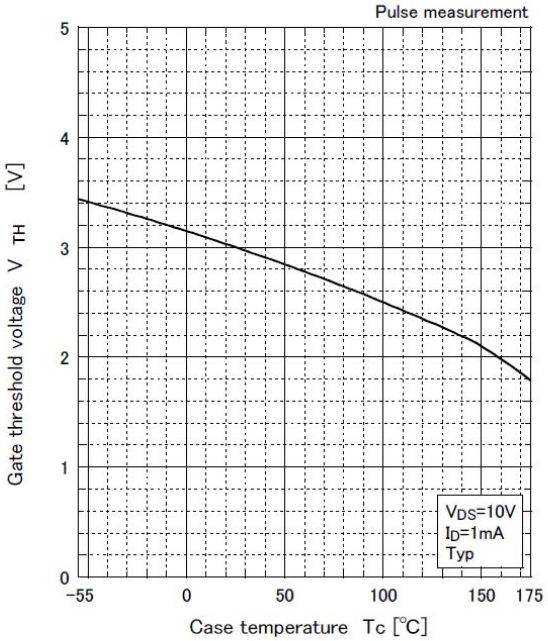
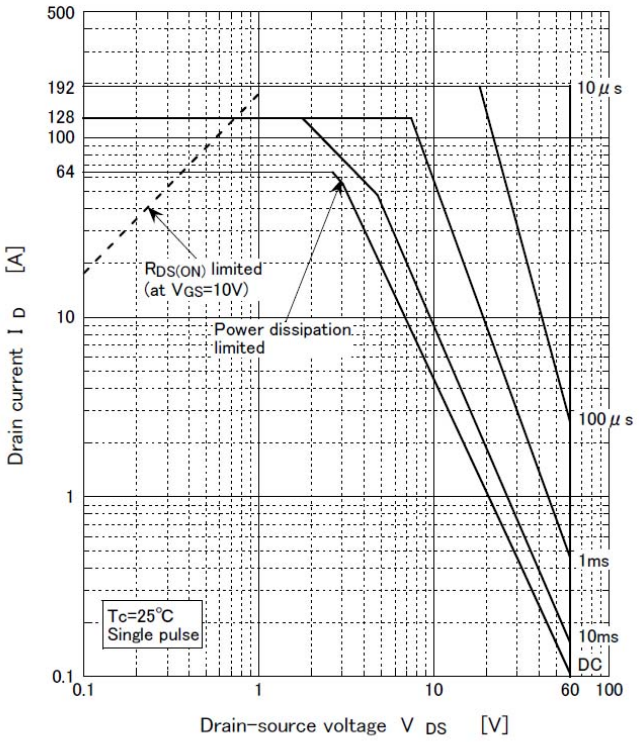
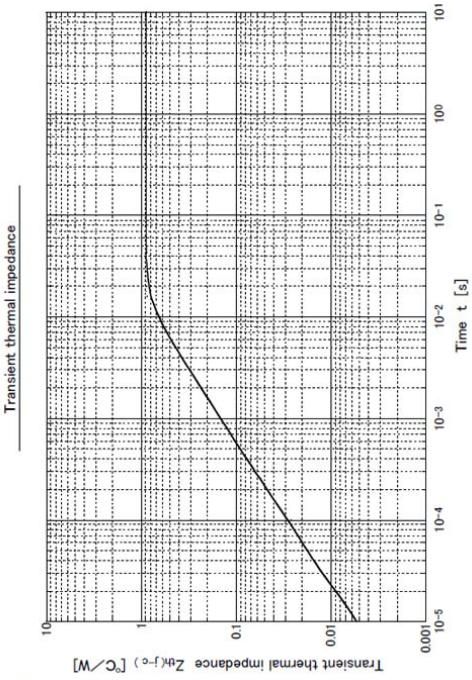
Gate threshold voltage
vs case temperature



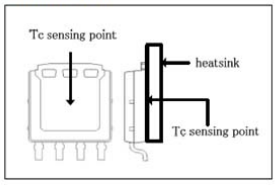
Safe operating area



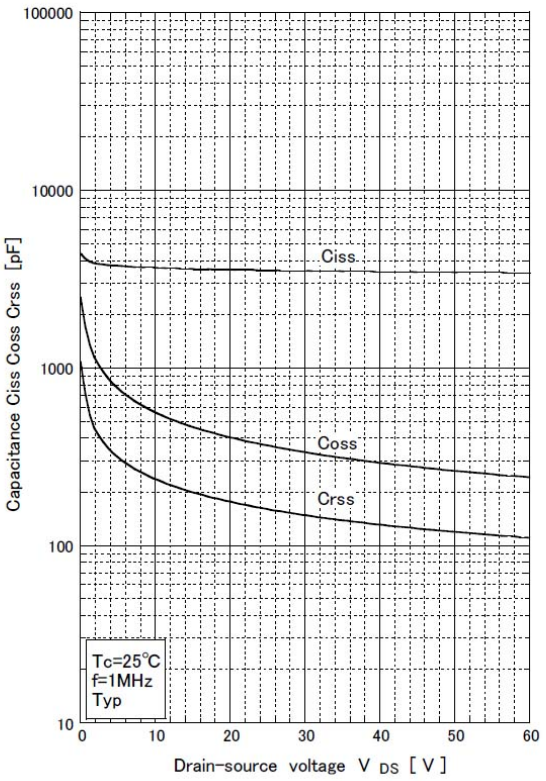
Transient thermal impedance



Tc sensing point



Capacitance characteristics



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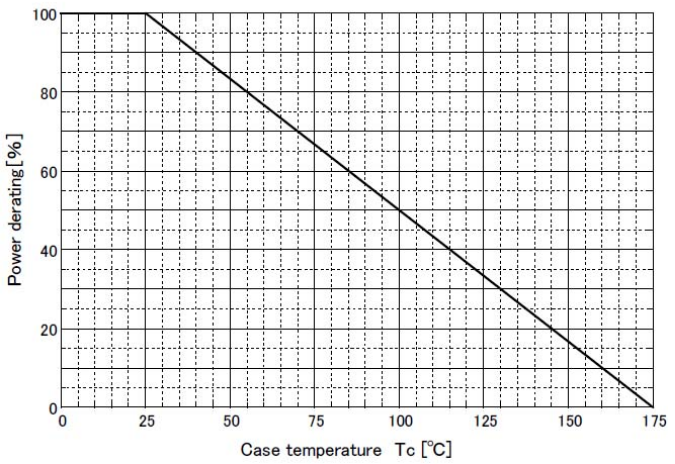
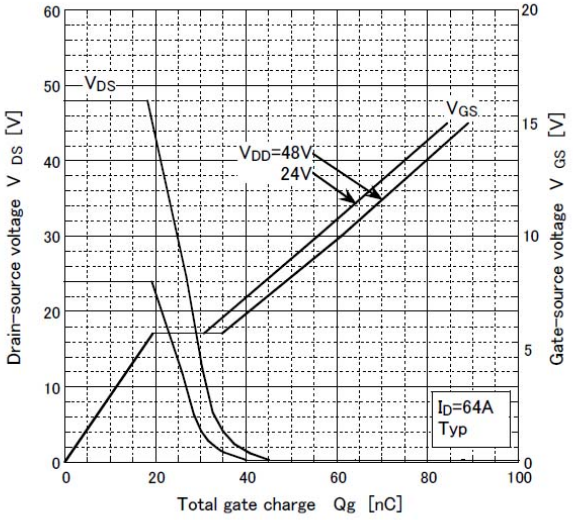
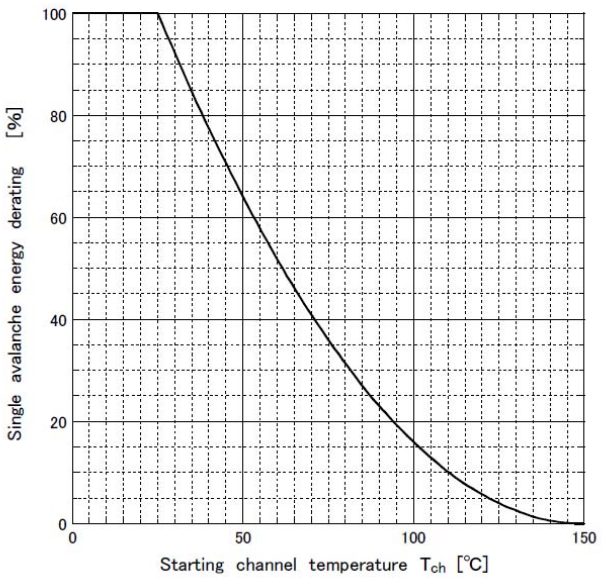
Power derating – case temperature



Gate charge characteristics



Single avalanche energy derating
vs channel temperature



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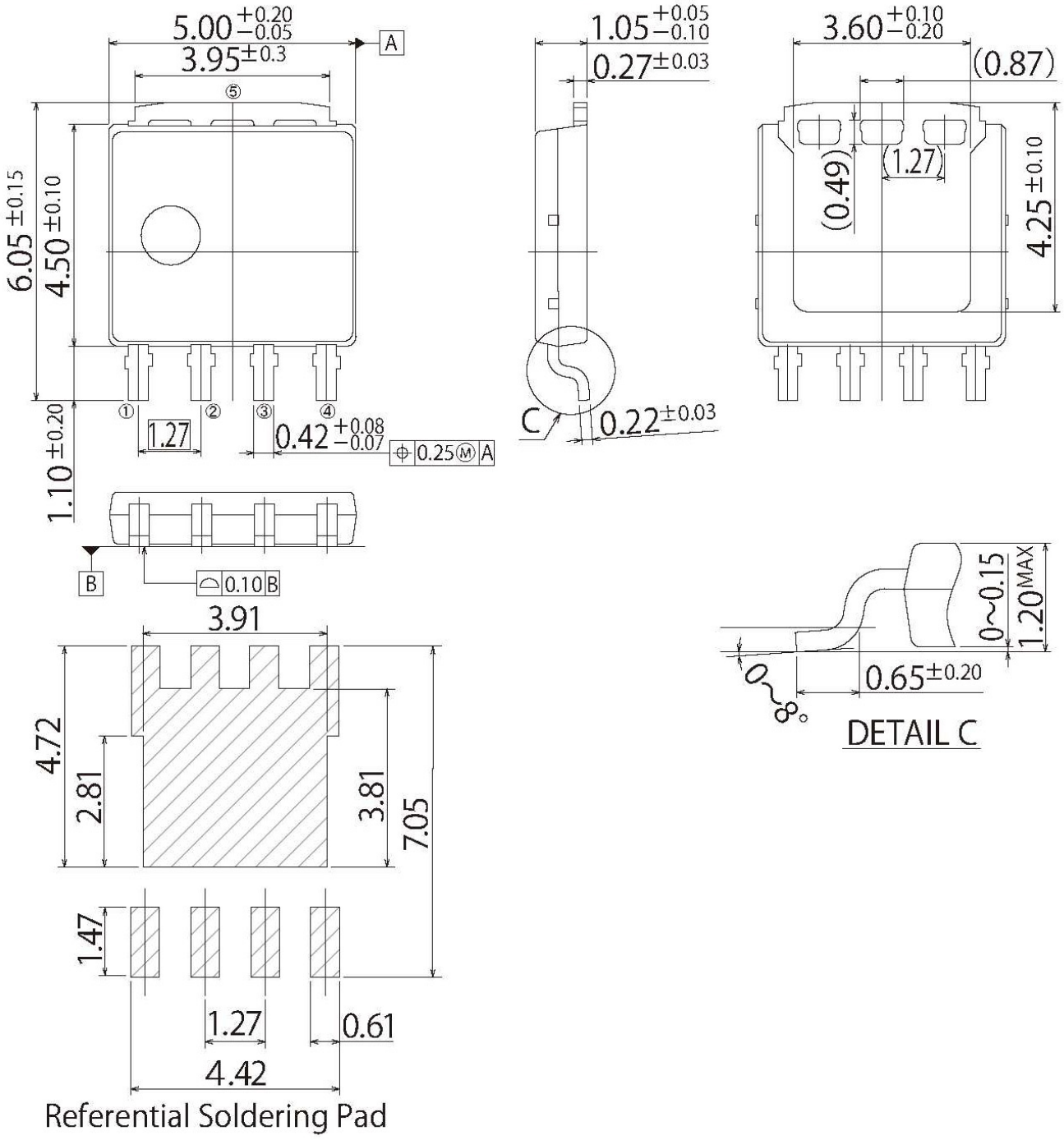
Outline Dimensions

unit:mm

G7

JEDEC Code	MO-235B similar
JEITA Code	–
House Name	LF



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